International Rectifier

MBRS340TR

SCHOTTKY RECTIFIER

3 Amp

 $I_{F(AV)} = 3.0 Amp$ $V_R = 40 V$

Major Ratings and Characteristics

<u>, </u>		
Characteristics	Value	Units
I _{F(AV)} Rectangular waveform	3.0	А
V _{RRM}	40	V
I _{FSM} @t _p =5µs sine	1580	Α
V _F @3.0Apk,T _J =125°C	0.43	V
T _J range	- 55 to 150	°C

Description/Features

The MBRS340TR surface-mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Small foot print, surface mountable
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



Bulletin PD-20585 rev. E 07/04

International TOR Rectifier

Voltage Ratings

	Part number	MBRS340TR
V_R	Max. DC Reverse Voltage (V)	40
V _{RWI}	Max. Working Peak Reverse Voltage (V)	

Absolute Maximum Ratings

	Parameters	Value	Units	Conditions	
I _{F(AV)}	Max. Average Forward Current	3.0	Α	50% duty cycle @ T _L = 118 °C, rectangular wave form	
		4.0		50% duty cycle @ T _L = 110 °C, r	ectangular waveform
I _{FSM}	Max. Peak One Cycle Non-Repetitive	1580	Α	5μs Sine or 3μs Rect. pulse	Following any rated load condition and
	SurgeCurrent	80		10ms Sine or 6ms Rect. pulse	with rated V _{RRM} applied
E _{AS}	Non Repetitive Avalanche Energy	6	mJ	T _J =25°C, I _{AS} =1.0A, L=12mH	
I _{AR}	Repetitive Avalanche Current	1.0	А	Current decaying linearly to zero Frequency limited by T _J max. V	

Electrical Specifications

	Parameters		Value	Units	Conditions	
V _{FM}	Max. Forward Voltage Drop ((1)	0.525	V	@ 3A	T 05 %0
''''			0.68	V	@ 6A	T _J = 25 °C
			0.43	V	@ 3A	T 407.00
			0.57	V	@ 6A	T _J = 125 °C
I _{RM}	Max. Reverse Leakage (1	1)	2.0	mA	T _J = 25 °C	
	Current		20	mA	T _J = 100°C	V _R = rated V _R
			35	mA	T _J = 125 °C	
C _T	Max. Junction Capacitance		230	pF	V _R = 5V _{DC} (test signal range 100KHz to 1Mhz) 25°C	
Ls	Typical Series Inductance		3.0	nH	Measured lead to lead 5mm from package body	
dv/dt	Max. Voltage Rate of Change		10000	V/µs	(Rated V _R)	

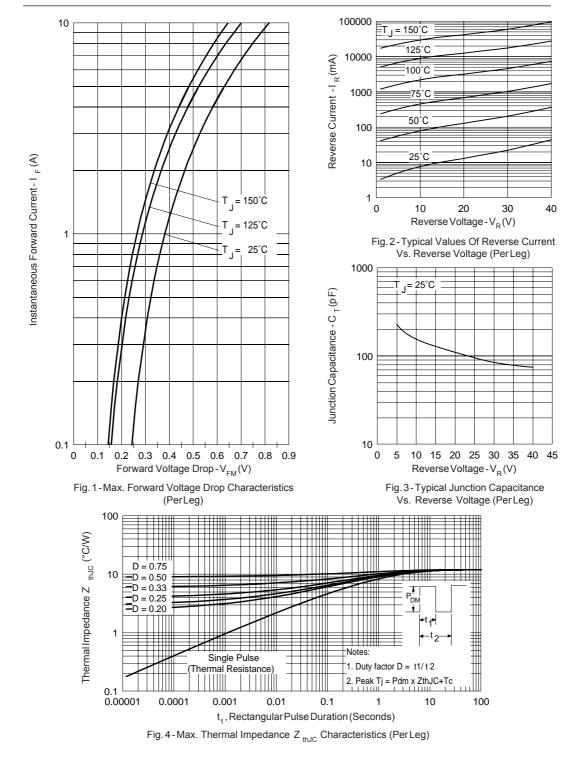
⁽¹⁾ Pulse Width < 300µs, Duty Cycle < 2%

Thermal-Mechanical Specifications

	Parameters	Value	Units	Conditions
T _J	Max.JunctionTemperatureRange (*)	-55 to 150	°C	
T _{stg}	Max.StorageTemperatureRange	-55 to 150	°C	
R _{thJL}	Max.Thermal Resistance Junction to Lead (**)	12	°C/W	DCoperation
R _{thJA}	Max.Thermal Resistance Junction to Ambient	46	°C/W	DCoperation
wt	Approximate Weight	0.24(0.008)	g(oz.)	
	Case Style	SMC		Similar to DO-214AB
	Device Marking	IR34		

 $[\]frac{\text{(*)}}{\text{dTj}} < \frac{\text{dPtot}}{\text{Rth(j-a)}} < \frac{1}{\text{Rth(j-a)}} \qquad \text{thermal runaway condition for a diode on its own heatsink}$

^(**) Mounted 1 inch square PCB



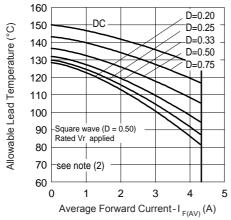


Fig. 4-Maximum Average Forward Current Vs. Allowable Lead Temperature

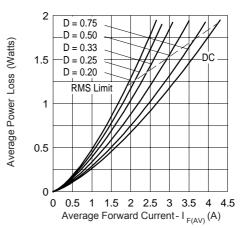


Fig. 5 - Maximum Average Forward Dissipation Vs. Average Forward Current

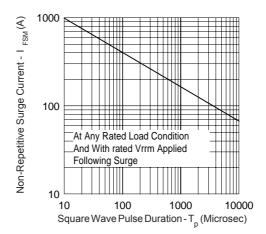
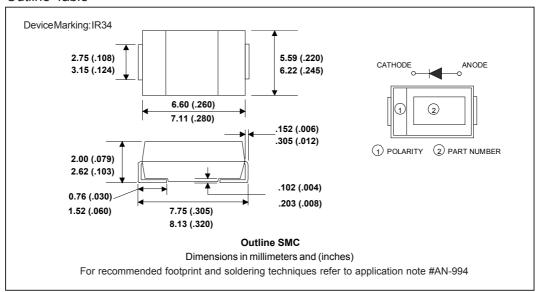


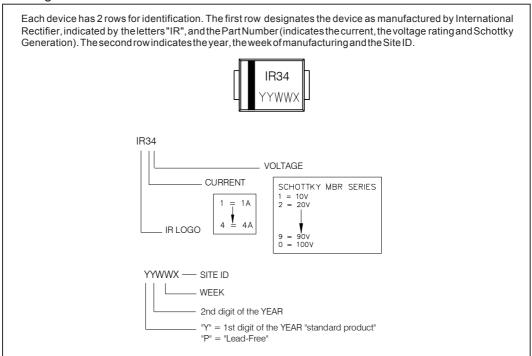
Fig. 6 - Maximum Peak Surge Forward Current Vs. Pulse Duration

 $\begin{tabular}{ll} \textbf{(2)} & Formula used: $T_C = T_J - (Pd + Pd_{REV})$ x R_{thJC}; \\ & Pd = Forward Power Loss = $I_{F(AV)}$ x $V_{FM}@(I_{F(AV)}/D)$ (see Fig. 6); \\ & Pd_{REV} = Inverse Power Loss = V_{R1} x $I_R(1-D)$; $I_R@V_{R1} = 80\%$ rated V_R. \\ \end{tabular}$

Outline Table

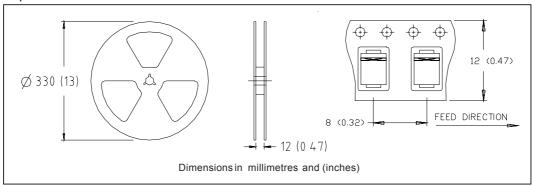


Marking & Identification

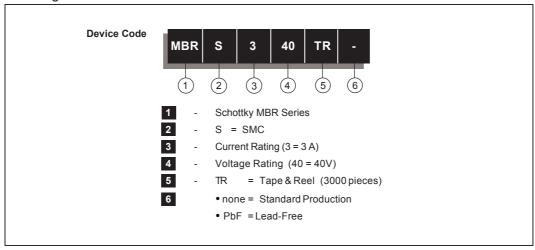


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Tape & Reel Information



Ordering Information Table



Data and specifications subject to change without notice. This product has been designed and qualified for Industrial Level.

Qualification Standards can be found on IR's Web site.



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